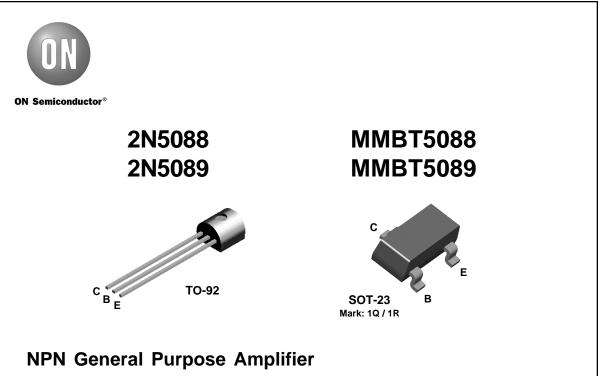
**ON Semiconductor** 

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# Onsemi

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This device is designed for low noise, high gain, general purpose amplifier applications at collector currents from  $1\mu$ A to 50 mA.

#### Absolute Maximum Ratings\* TA = 25°C unless otherwise noted

Symbol	Parameter		Value	Units
V <sub>CEO</sub>	Collector-Emitter Voltage	2N5088 2N5089	30 25	V V
V <sub>CBO</sub>	Collector-Base Voltage	2N5088 2N5089	35 30	V V
V <sub>EBO</sub>	Emitter-Base Voltage		4.5	V
Ic	Collector Current - Continuous		100	mA
T <sub>J</sub> , T <sub>stg</sub>	Operating and Storage Junction Temperature Range		-55 to +150	°C

\*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

### Thermal Characteristics TA = 25°C unless otherwise noted

Symbol	Characteristic	Мах		Units	
		2N5088 2N5089	*MMBT5088 *MMBT5089		
P <sub>D</sub>	Total Device Dissipation	625	350	mW	
	Derate above 25°C	5.0	2.8	mW/°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3		°C/W	
$R_{ ext{ hetaJA}}$	Thermal Resistance, Junction to Ambient	200	357	°C/W	

\*Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

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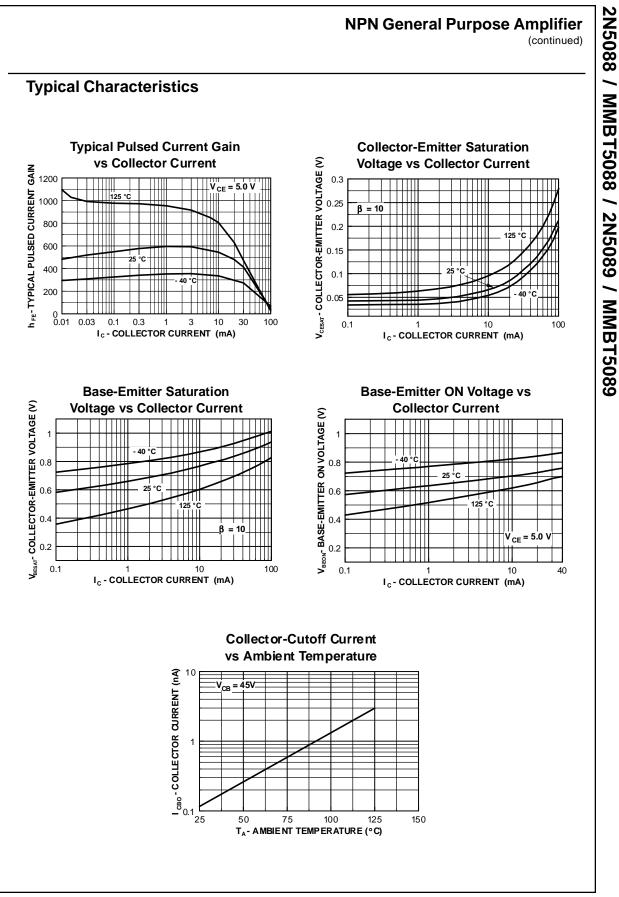
		NPN General Purpose Amplifier (continued)				
Electrical Characteristics TA=25°C unless otherwise noted						
Symbol	Parameter	Test Conditions	Min	Max	Units	
OFF CHAF	ACTERISTICS					
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage*	$I_{\rm C} = 1.0 \text{ mA}, I_{\rm B} = 0$ 5088 5089	30 25		V V	
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	$I_{\rm C} = 100 \ \mu {\rm A}, \ I_{\rm E} = 0$ 5088 5089	35 30		V V	
I <sub>CBO</sub>	Collector Cutoff Current	$V_{CB} = 20 V, I_E = 0$ 5088 $V_{CB} = 15 V, I_E = 0$ 5089		50 50	nA nA	
I <sub>EBO</sub>	Emitter Cutoff Current	$V_{EB} = 3.0 \text{ V}, I_C = 0$ $V_{EB} = 4.5 \text{ V}, I_C = 0$		50 100	nA nA	
ON CHAR	ACTERISTICS					
h <sub>FE</sub>	DC Current Gain	$\label{eq:loss} \begin{array}{l} I_{C} = 100 \; \mu \text{A},  V_{CE} = 5.0 \; \text{V} & \begin{array}{c} \textbf{5088} \\ \textbf{5089} \\ I_{C} = 1.0 \; \text{mA},  V_{CE} = 5.0 \; \text{V} & \begin{array}{c} \textbf{5088} \\ \textbf{5089} \\ I_{C} = 10 \; \text{mA},  V_{CE} = 5.0 \; \text{V}^{\star} & \begin{array}{c} \textbf{5088} \\ \textbf{5089} \\ \textbf{5089} \end{array} \end{array}$	300 400 350 450 300 400	900 1200		
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	Ic = 10 mA, I <sub>B</sub> = 1.0 mA		0.5	V	
V <sub>BE(on)</sub>	Base-Emitter On Voltage	$I_{C} = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}$		0.8	V	
	GNAL CHARACTERISTICS					
f <sub>T</sub>	Current Gain - Bandwidth Product	$I_{C} = 500 \ \mu A, V_{CE} = 5.0 \ m A, f = 20 \ MHz$	50	10	MHz	

f⊤	Current Gain - Bandwidth Product	$I_{C} = 500 \ \mu A, V_{CE} = 5.0 \ mA, f = 20 \ MHz$	50		MHz
C <sub>cb</sub>	Collector-Base Capacitance	$V_{CB} = 5.0 \text{ V}, I_E = 0, f = 100 \text{ kHz}$		4.0	pF
C <sub>eb</sub>	Emitter-Base Capacitance	$V_{BE} = 0.5 \text{ V}, I_{C} = 0, f = 100 \text{ kHz}$		10	pF
h <sub>fe</sub>	Small-Signal Current Gain	$ I_{C} = 1.0 \text{ mA}, V_{CE} = 5.0 \text{ V},  \textbf{5088} \\ f = 1.0 \text{ kHz} \qquad \textbf{5089} $	350 450	1400 1800	
NF	Noise Figure			3.0 2.0	dB dB

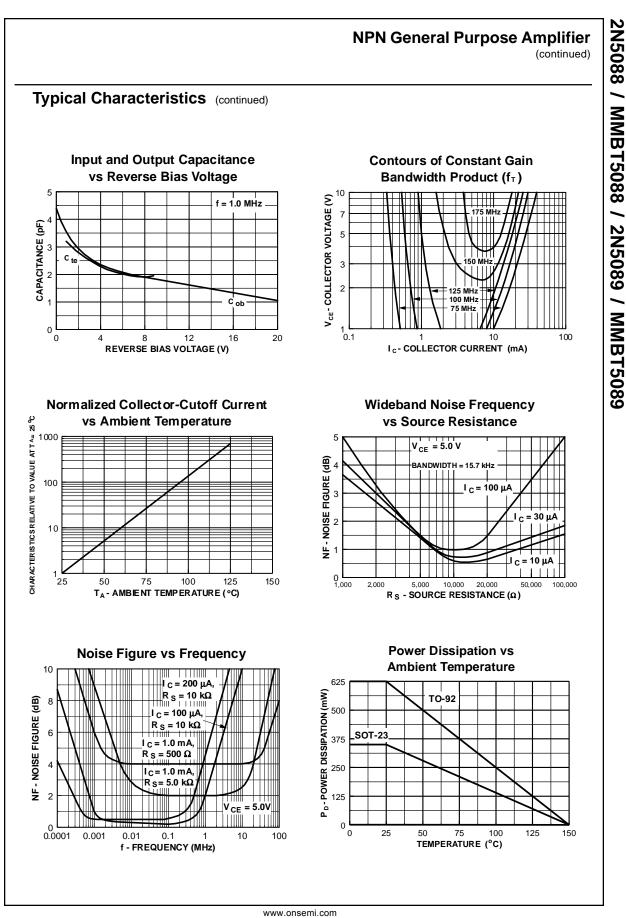
\*Pulse Test: Pulse Width  ${\leq}\,300\,\mu\text{s},\,\text{Duty}\,\text{Cycle}\,{\leq}\,2.0\%$ 

# **Spice Model**

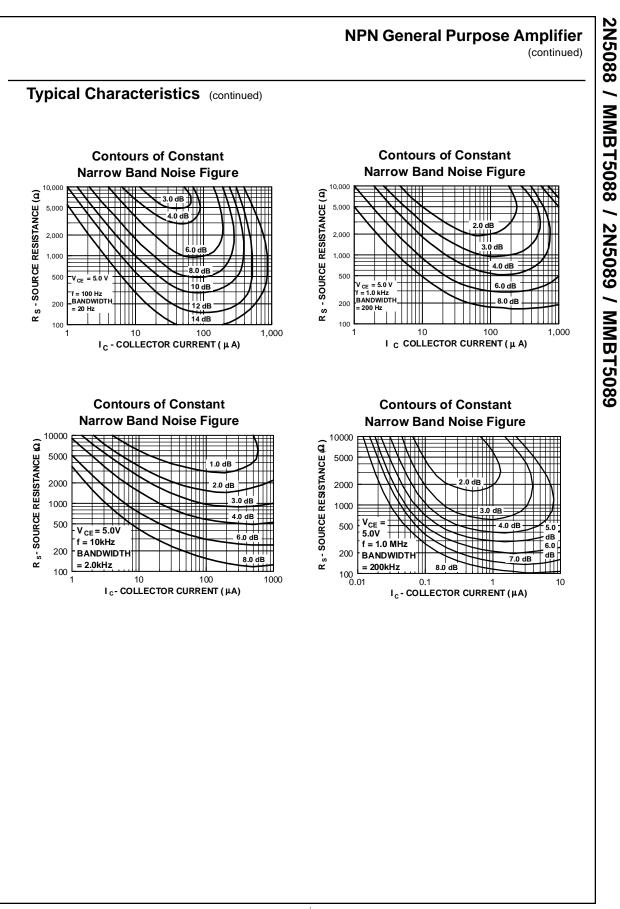
NPN (Is=5.911f Xti=3 Eg=1.11 Vaf=62.37 Bf=1.122K Ne=1.394 Ise=5.911f Ikf=14.92m Xtb=1.5 Br=1.271 Nc=2 Isc=0 lkr=0 Rc=1.61 Cjc=4.017p Mjc=.3174 Vjc=.75 Fc=.5 Cje=4.973p Mje=.4146 Vje=.75 Tr=4.673n Tf=821.7p Itf=.35 Vtf=4 Xtf=7 Rb=10)



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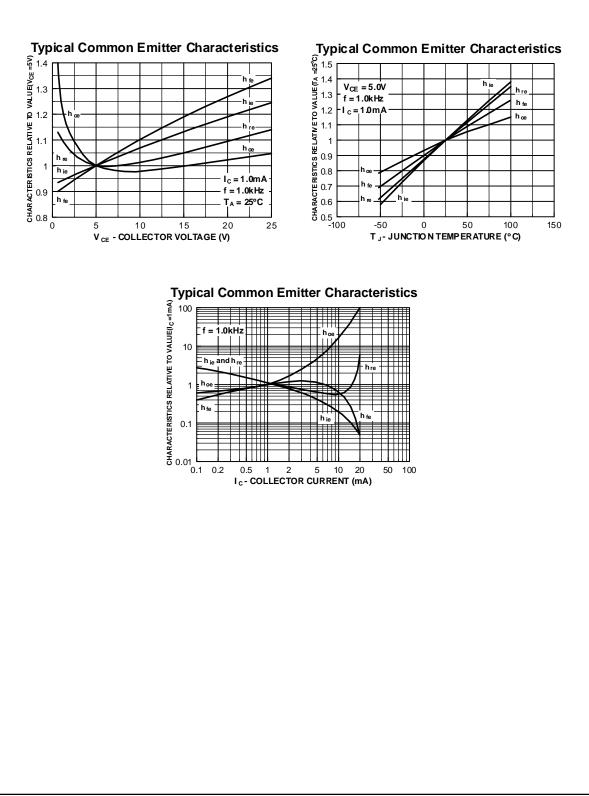
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#### NPN General Purpose Amplifier (continued)

## Typical Common Emitter Characteristics (f = 1.0 kHz)



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